

MOSFETs Silicon P-Channel MOS (U-MOSVI)

SSM6J424TU

1. Applications

· Power Management Switches

2. Features

- (1) AEC-Q101 qualified (Note 1)
- (2) 1.5-V gate drive voltage.
- (3) Low drain-source on-resistance
 - : $R_{DS(ON)} = 54 \text{ m}\Omega \text{ (max) } (@V_{GS} = -1.5 \text{ V})$

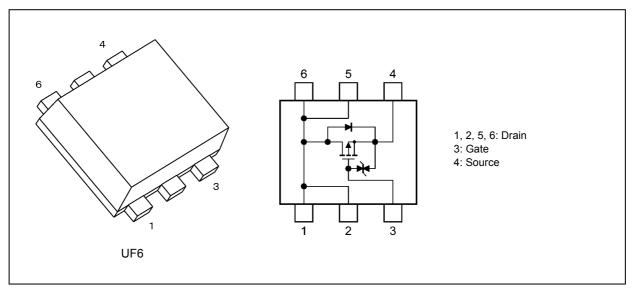
 $R_{DS(ON)} = 36 \text{ m}\Omega \text{ (max) (@V_{GS} = -1.8 V)}$

 $R_{\rm DS(ON)} = 26~{\rm m}\Omega~({\rm max})~(@V_{\rm GS} = -2.5~{\rm V})$

 $R_{\mathrm{DS(ON)}}$ = 22.5 m Ω (max) (@V_{GS} = -4.5 V)

Note 1: For detail information, please contact to our sales.

3. Packaging and Pin Configuration





4. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25°C)

Ch	aracteristics	Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	-20	V
Gate-source voltage		V _{GSS}	-8/+6	
Drain current (DC)		I _D	-6	Α
Drain current (pulsed)	(Note 1)	I _{DP}	-14	
Power dissipation	(Note 2)	P _D	1	W
Channel temperature		T _{ch}	150	°C
Storage temperature		T _{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width (PW) \leq 10 ms, duty \leq 1%

Note 2: Device mounted on an FR4 board.(25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 645 mm²)

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance, R_{th(ch-a)}, and the power dissipation, P_D, vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.

2018-03-27



5. Electrical Characteristics

5.1. Static Characteristics (T_a = 25°C unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = -8/+6 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μΑ
Drain cut-off current		I _{DSS}	V _{DS} = -20 V, V _{GS} = 0 V	_		-1	
Drain-source breakdown voltage		V _{(BR)DSS}	I_D = -1 mA, V_{GS} = 0 V	-20			V
Drain-source breakdown voltage	(Note 1)	V _{(BR)DSX}	I_D = -1 mA, V_{GS} = 5 V	-15			
Gate threshold voltage	(Note 2)	V_{th}	$V_{DS} = -3 \text{ V}, I_{D} = -1 \text{ mA}$	-0.3	_	-1.0	
Drain-source on-resistance	(Note 3)	R _{DS(ON)}	$I_D = -6.0 \text{ A}, V_{GS} = -4.5 \text{ V}$	_	18	22.5	mΩ
			$I_D = -5.5 \text{ A}, V_{GS} = -2.5 \text{ V}$	_	21	26	
			$I_D = -3.0 \text{ A}, V_{GS} = -1.8 \text{ V}$	_	25	36	
			I _D = -1.5 A, V _{GS} = -1.5 V	_	29	54	
Forward transfer admittance	(Note 3)	Y _{fs}	$V_{DS} = -3 \text{ V}, I_{D} = -2.0 \text{ A}$	9.1	18.2		S

Note 1: If a reverse bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

Note 2: Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (-1 mA for this device). Then, for normal switching operation, $V_{GS(ON)}$ must be higher than V_{th} , and $V_{GS(OFF)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$.

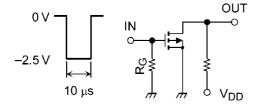
Take this into consideration when using the device.

Note 3: Pulse measurement.

5.2. Dynamic Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V},$	1	1650		pF
Reverse transfer capacitance	C _{rss}	f = 1 MHz		90		
Output capacitance	Coss			220		
Switching time (turn-on time)	t _{on}	V_{DD} = -10 V, I_{D} = -2.0 A V_{GS} = 0 to -2.5 V, R_{G} = 4.7 Ω ,		77		ns
Switching time (turn-off time)	t _{off}	Duty \leq 1%, Input: t_r , t_f < 5 ns Common source, See Chapter 5.3	_	206	_	

5.3. Switching Time Test Circuit



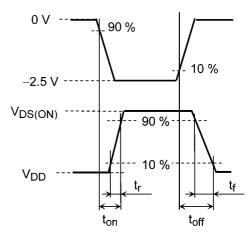


Fig. 5.3.1 Test Circuit of Switching Time

Fig. 5.3.2 Input Waveform/Output Waveform



5.4. Gate Charge Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	$V_{DD} = -10 \text{ V}, V_{GS} = -4.5 \text{ V},$	_	23.1	_	nC
Gate-source charge 1	Q _{gs1}	$I_D = -6.0 \text{ A}$	_	3.8	_	
Gate-drain charge	Q _{gd}		_	4.1	_	

5.5. Source-Drain Characteristics (T_a = 25°C unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	(Note 1)	V_{DSF}	I _D = 6.0 A, V _{GS} = 0 V	_	0.74	1.2	V

Note 1: Pulse measurement.

6. Marking

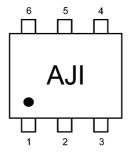


Fig. 6.1 Marking



7. Characteristics Curves (Note)

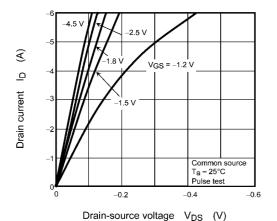


Fig. 7.1 I_D - V_{DS}

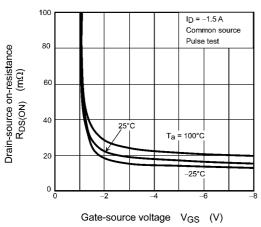


Fig. 7.3 R_{DS(ON)} - V_{GS}

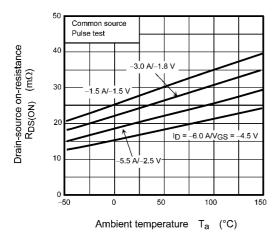


Fig. 7.5 R_{DS(ON)} - T_a

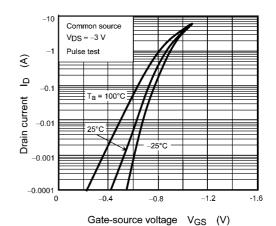


Fig. 7.2 I_D - V_{GS}

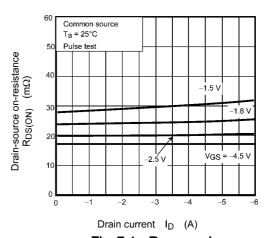


Fig. 7.4 R_{DS(ON)} - I_D

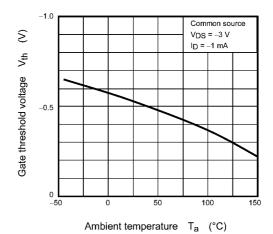
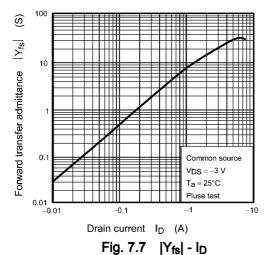


Fig. 7.6 V_{th} - T_a





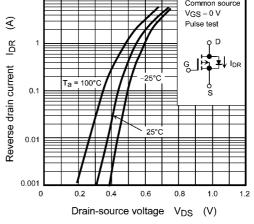


Fig. 7.8 I_{DR} - V_{DS}

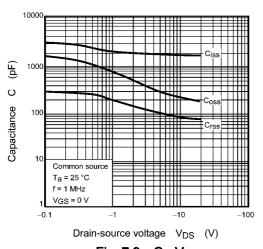


Fig. 7.9 $\,$ C - V_{DS}

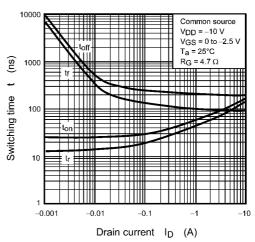


Fig. 7.10 t-I_D

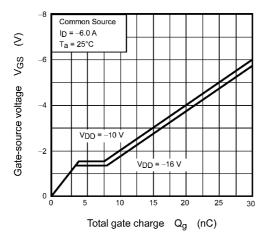


Fig. 7.11 Dynamic Input/Output Characteristics

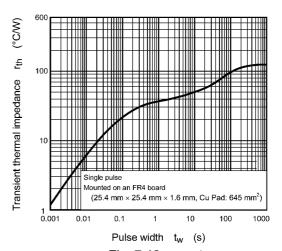
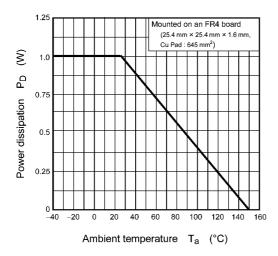


Fig. 7.12 rth - tw





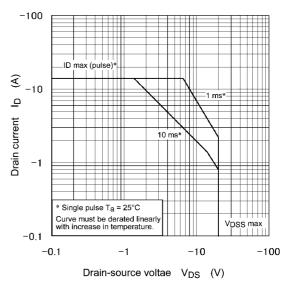


Fig. 7.13 P_D - T_a

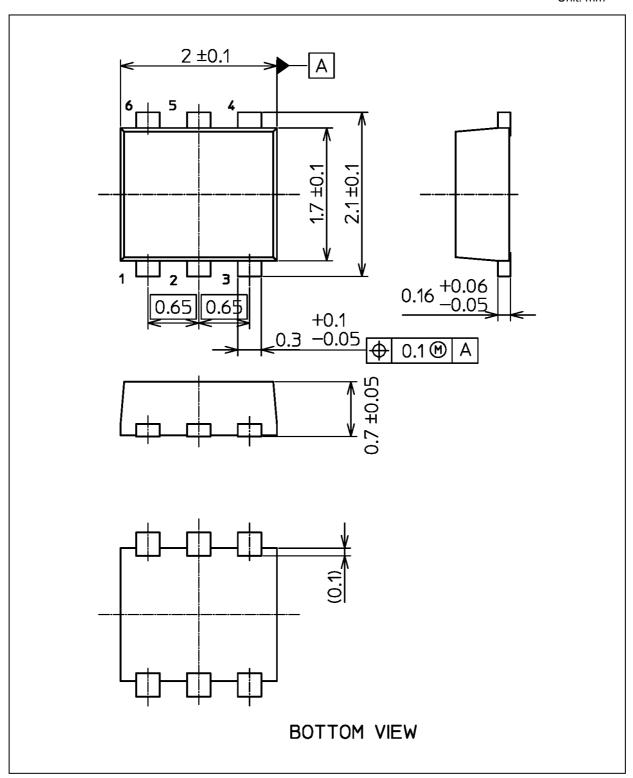
Fig. 7.14 Safe Operating Area

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 7.0 mg (typ.)

Pa	ckage Name(s)
TOSHIBA: 2-2T1S	
Nickname: UF6	

Rev.1.0



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